

# 8 MBd Low Input Current Optocoupler

# **Technical Data**

#### **Features**

- Guaranteed Low Thresholds:  $I_F = 0.5 \text{ mA}, V_F \leq 1.5 \text{ V}$
- High Speed: Guaranteed 5 MBd over Temperature
- Versatile: Compatible with TTL, LSTTL and CMOS
- Efficient 820 nm AlGaAs LED
- Internal Shield for Guaranteed Common Mode Rejection
- Schottky Clamped, Open Collector Output with Optional Integrated Pull-Up Resistor
- Static and Dynamic Performance Guaranteed from -40°C to 85°C
- Safety Approval

  UL Recognized -2500 V rms for

  1 minute

  CSA Approved

  VDE 0884 Approved with

  V<sub>IORM</sub> = 630 V <sub>peak</sub>

  (Option 060)

#### **Applications**

- Ground Loop Elimination
- Computer-Peripheral Interfaces
- Level Shifting

- Microprocessor System Interfaces
- Digital Isolation for A/D, D/A Conversion
- RS-232-C Interface
- High Speed, Long Distance Isolated Line Receiver

## **Description**

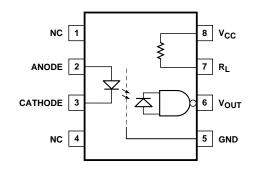
The HCPL-2300 optocoupler combines an 820 nm AlGaAs photon emitting diode with an integrated high gain photon detector. This combination of

#### **HCPL-2300**

Hewlett-Packard designed and manufactured semiconductor devices brings new high performance capabilities to designers of isolated logic and data communication circuits.

The new low current, high speed AlGaAs emitter manufactured with a unique diffused junction, has the virtue of fast rise and fall times at low drive currents. Figure 6 illustrates the propagation delay vs. input current characteristic. These unique

#### **Functional Diagram**



A 0.1 pF bypass capacitor must be connected between pins 5 and 8.

CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

characteristics enable this device to be used in an RS-232-C interface with ground loop isolation and improved common mode rejection. As a line receiver, the HCPL-2300 will operate over longer line lengths for a given data rate because of lower  $I_{\rm F}$  and  $V_{\rm F}$  specifications.

The output of the shielded integrated detector circuit is an open

collector Schottky clamped transistor. The shield, which shunts capacitively coupled common mode noise to ground, provides a guaranteed transient immunity specification of  $100~V/\mu s$ . The output circuit includes an optional integrated  $1000~\Omega$  pullup resistor for the open collector. This gives designers the flexibility to use the internal resistor for pull-up to five volt logic or to use

an external resistor for connection to supply voltages up to 18 V (CMOS logic voltage).

The Electrical and Switching Characteristics of the HCPL-2300 are guaranteed over a temperature range of -40°C to 85°C. This enables the user to confidently design a circuit which will operate under a broad range of operating conditions.

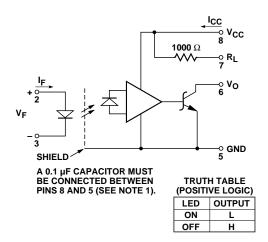
## **Ordering Information**

Specify part number followed by Option Number (if desired).

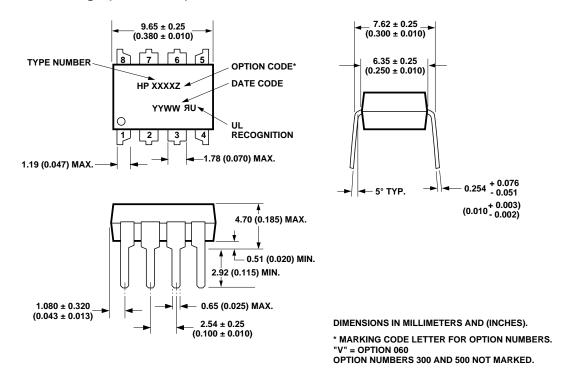


Option data sheets available. Contact your Hewlett-Packard sales representative or authorized distributor for information.

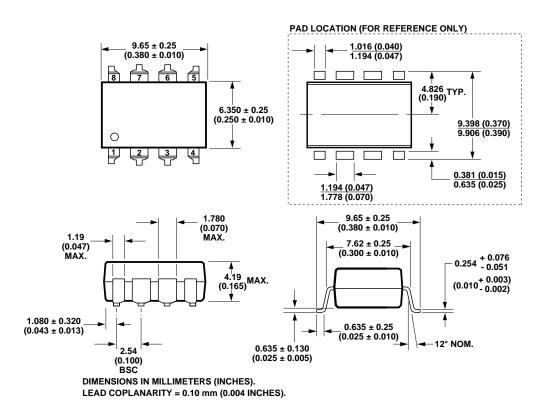
## Schematic



## Package Outline Drawings 8-Pin DIP Package (HCPL-2300)



### 8-Pin DIP Package with Gull Wing Surface Mount Option 300 (HCPL-2300)



# Thermal Profile (Option #300)

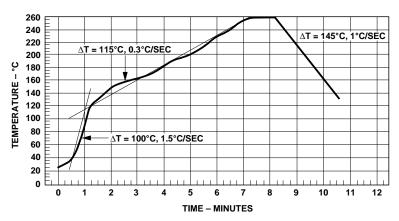


Figure 1. Maximum Solder Reflow Thermal Profile. (Note: Use of non-chlorine activated fluxes is recommended.)

## **Regulatory Information**

#### CSA

The HCPL-2300 has been approved by the following organizations:

Approved under CSA Component Acceptance Notice #5, File CA 88324.

UL VDE

Recognized under UL 1577, Component Recognition Program, File E55361. Approved according to VDE 0884/06.92 (Option 060 only)

# **Insulation and Safety Related Specifications**

Parameter	Symbol	Value	Units	Conditions
Min. External Air Gap (External Clearance)	L(IO1)	7.1	mm	Measured from input terminals to output terminals, shortest distance through air
Min. External Tracking Path (External Creepage)	L(IO2)	7.4	mm	Measured from input terminals to output terminals, shortest distance path along body
Min. Internal Plastic Gap (Internal Clearance)		0.08	mm	Through insulation distance, conductor to conductor, usually the direct distance between the photoemitter and photodetector inside the optocoupler cavity
Tracking Resistance (Comparative Tracking Index)	CTI	200	Volts	DIN IEC 112/VDE 0303 PART 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

Option 300 - surface mount classification is Class A in accordance with CECC 00802.

# VDE 0884 Insulation Related Characteristics (HCPL-2300 Option 060 ONLY)

Description	Symbol	Characteristic	Units
Installation classification per DIN VDE 0110/1.89, Table 1			
for rated mains voltage ≤ 300 V rms		I-IV	
for rated mains voltage ≤ 450 V rms		I-III	
Climatic Classification		55/85/21	
Pollution Degree (DIN VDE 0110/1.89)		2	
Maximum Working Insulation Voltage	V <sub>IORM</sub>	630	V peak
Input to Output Test Voltage, Method b* $V_{IORM} \ x \ 1.875 = V_{PR}, \ 100\% \ Production \ Test \ with \ t_m = 1 \ sec, \\ Partial \ Discharge < 5 \ pC$	$ m V_{PR}$	1181	V peak
Input to Output Test Voltage, Method a* $V_{IORM} \times 1.5 = V_{PR}$ , Type and sample test, $t_m = 60$ sec, Partial Discharge < 5 pC	$ m V_{PR}$	945	V peak
Highest Allowable Overvoltage* (Transient Overvoltage, t <sub>ini</sub> = 10 sec)	$V_{IOTM}$	6000	V peak
Safety Limiting Values (Maximum values allowed in the event of a failure, also see Figure 11, Thermal Derating curve.)			
Case Temperature	$T_{S}$	175	°C
Input Current	$I_{S,INPUT}$	230	mA
Output Power	$P_{S,OUTPUT}$	600	mW
Insulation Resistance at $T_S$ , $V_{IO} = 500 \text{ V}$	$R_{S}$	≥ 10 <sup>9</sup>	Ω

<sup>\*</sup>Refer to the front of the optocoupler section of the current catalog, under Product Safety Regulations section, (VDE 0884), for a detailed description.

Note: Isolation characteristics are guaranteed only within the safety maximum ratings which must be ensured by protective circuits in application.

# **Absolute Maximum Ratings**

(No Derating Required up to 55°C)

Storage Temperature, T <sub>S</sub>	55°C to +125°C
Operating Temperature, T <sub>A</sub>	40°C to +85°C
Lead Solder Temperature, max	260°C for 10 s
	(1.6 mm below seating plane)
Average Forward Input Current - I <sub>F</sub>	5 mA <sup>[2]</sup>
Reverse Input Voltage, V <sub>R</sub>	
Supply Voltage, V <sub>CC</sub>	0 V to 7.0 V
Pull-Up Resistor Voltage, V <sub>RL</sub>	0.5 V to V <sub>CC</sub>
Output Collector Current, I <sub>O</sub>	25 to 25 mA
Input Power Dissipation, P <sub>I</sub>	10 mW
Output Collector Power Dissipation, Po	40 mW
Output Collector Voltage, Vo	0.5 V to 18 V
Infrared and Vapor Phase Reflow Temperate	ure
(Option #300)	see Fig. 1, Thermal Profile

# **Recommended Operating Conditions**

Parameter	Symbol	Min.	Max.	Units	
Input Voltage, Low Level		$ m V_{FL}$	-2.5	0.8	V
Input Current High Level	0°C to 85°C	$I_{\mathrm{FH}}$	0.5	1.0	mA
	-40°C to 85°C		0.5	0.75	
Supply Voltage, Output		$V_{\rm CC}$	4.75	5.25	V
Fan Out (TTL Load)		N		5	
Operating Temperature		T <sub>A</sub>	-40	85	°C

# **DC Electrical Specifications**

For -40°C  $\leq$   $T_A \leq$  85°C, 4.75 V  $\leq$   $V_{CC} \leq$  5.25 V,  $V_{FL} \leq$  0.8 V, unless otherwise specified. All typicals at  $T_A =$  25°C and  $V_{CC} =$  5 V , unless otherwise specified. See note 1.

Parameter	Symbol	Min.	Тур.	Max.	Units	Test Conditions	Fig.	Note
High Level Output	$I_{OH}$		0.05	250	μA	$V_F = 0.8 \text{ V}, V_O = 18 \text{ V}$	4	
Current								
Low Level Output	$V_{OL}$		0.4	0.5	V	$I_F = 0.5 \text{ mA}$	3	
Voltage						$I_{OL}$ (Sinking) = 8 mA		
High Level Supply	$I_{CCH}$		4.0	6.3	mA	$I_{\rm F} = 0$ mA, $V_{\rm CC} = 5.25$ V		
Current								
Low Level Supply Current	$I_{CCL}$		6.2	10.0	mA	$I_F = 1.0 \text{ mA}, V_{CC} = 5.25 \text{ V}$		
Input Forward Voltage	$V_{\mathrm{F}}$	1.0	1.3	1.5	V	$T_{\rm A} = 25^{\circ}{\rm C}$ $I_{\rm F} = 1.0 \text{ mA}$	2	
		0.85		1.65				
Input Diode Temperature	$\Delta V_{ m F}$		-1.6		mV/°C	$I_F = 1.0 \text{ mA}$		
Coefficient	$\overline{\Delta T_{\!A}}$							
Input Reverse	$BV_R$	3.0			V	$I_R = 10 \mu A$		
Breakdown Voltage								
Input Capacitance	$C_{IN}$		18		pF	$V_F = 0 \text{ V}, f = 1 \text{ MHz}$		
Internal Pull-up Resistor	$R_{L}$	680	1000	1700	Ω	$T_A = 25$ °C		

# **Switching Specifications**

For -40°C  $\leq$   $T_A \leq$  85°C, 0.5 mA  $\leq$   $I_{FH} \leq$  0.75 mA; For 0°C  $\leq$   $T_A \leq$  85°C, 0.5 mA  $\leq$   $I_{FH} \leq$  1.0 mA; With 4.75 V  $\leq$   $V_{CC} \leq$  5.25 V,  $V_{FL} \leq$  0.8 V, unless otherwise specified. All typicals at  $T_A =$  25°C and  $V_{CC} =$  5 V,  $I_{FH} =$  0.625 mA, unless otherwise specified. See note 1.

Parameter	Symbol	Min.	Тур.	Max.	Units	<b>Test Conditions</b>	Fig.	Note
Propagation Delay Time	$\mathrm{t_{PLH}}$		95		ns	$C_P = 0 \text{ pF}$	5, 6, 8	4, 8
to Logic High Output Level			85	160		$C_P = 20 \text{ pF}$	5, 8	
Propagation Delay Time	$ m t_{PHL}$		110		ns	$C_P = 0 \text{ pF}$	5, 6, 8	5, 8
to Logic Low Output Level			35	200		$C_P = 20 \text{ pF}$	5, 8	
Output Rise Time (10-90%)	$t_{\rm r}$		40		ns	$C_P = 20 \text{ pF}$	7, 8	8
Output Fall Time (90-10%)	$t_{\mathrm{f}}$		20		ns			
Common Mode Transient	$ \mathrm{CM_H} $	100	400		V/µs	$V_{CM} = 50 \text{ V (peak)},$	9, 10	6
Immunity at High						$V_{O}$ (min.) = 2 V,		
Output Level						$R_L = 560 \Omega$		
						$I_F = 0 \text{ mA}$		
Common Mode Transient	$ \mathrm{CM_L} $	100	400		V/µs	$V_{CM} = 50 \text{ V (peak)},$	9, 10	7
Immunity at Low						$V_0 \text{ (max.)} = 0.8 \text{ V},$		
Output Level						$R_L = 560 \Omega$		
						$I_{\rm F} = 0.5  {\rm mA}$		

### **Package Characteristics**

For -40°C  $\leq$  T<sub>A</sub>  $\leq$  85°C, unless otherwise specified. All typicals at T<sub>A</sub> = 25°C.

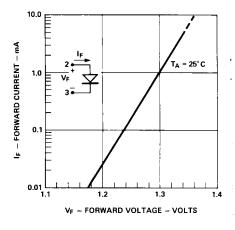
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Notes
Input-Output Momentary	V <sub>ISO</sub>	2500			V rms	$RH \le 50\%$ , $t = 1 min$ ,		3, 9
Withstand Voltage*						$T_A = 25$ °C		
Resistance, Input-Output	$R_{\text{I-O}}$		$10^{12}$		Ω	$V_{I-O} = 500 \text{ V}$		3
Capacitance, Input-Output	C <sub>I-O</sub>		0.6		pF	f = 1  MHz		3

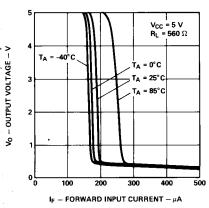
<sup>\*</sup>The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the VDE 0884 Insulation Characteristics Table (if applicable), your equipment level safety specification, or HP Application Note 1074, "Optocoupler Input-Output Endurance Voltage."

#### Notes:

- 1. Bypassing the power supply line is required with a  $0.1~\mu F$  ceramic disc capacitor adjacent to each optocoupler as illustrated in Figure 19. The power supply bus for the optocoupler(s) should be separate from the bus for any active loads, otherwise a larger value of bypass capacitor (up to  $0.5~\mu F$ ) may be needed to suppress regenerative feedback via the power supply.
- 2. Peaking circuits may produce transient input currents up to 100 mA, 500 ns maximum pulse width, provided average current does not exceed 5 mA.
- 3. Device considered a two terminal device: pins 1, 2, 3, and 4 shorted together, and pins 5, 6, 7, and 8 shorted together.
- 4. The t<sub>PLH</sub> propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.5 V point on the trailing edge of the output pulse.
- 5. The t<sub>PHL</sub> propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.5 V point on the leading edge of the output pulse.
- $\begin{array}{l} {\rm 6.~CM_{H}~is~the~maximum~tolerable~rate~of} \\ {\rm rise~of~the~common~mode~voltage~to} \\ {\rm assure~that~the~output~will~remain~in~a} \\ {\rm high~logic~state~(i.e.,~V_{OUT}>2.0~V)}. \end{array}$

- 7.  $CM_L$  is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state (i.e.,  $V_{OUT} < 0.8 \text{ V}$ ).
- 8.  $C_P$  is the peaking capacitance. Refer to test circuit in Figure 8.
- 9. In accordance with UL 1577, each optocoupler is momentary with stand proof tested by applying an insulation test voltage  $\geq 3000$  Vrms for 1 second (leakage detection current limit,  $I_{I\text{-}O} \leq 5~\mu\text{A}$ ). This test is performed before the 100% production test for partial discharge (Method b) shown in the VDE 0884 Insulation Characteristics Table, if applicable.





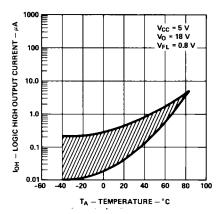
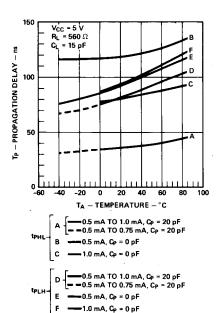
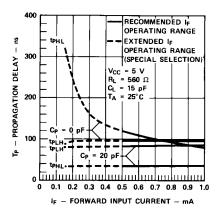


Figure 2. Typical Input Diode Forward Characteristics.

Figure 3. Typical Output Voltage vs. Forward Input Current vs. Temperature.

Figure 4. Typical Logic High Output Current vs. Temperature.





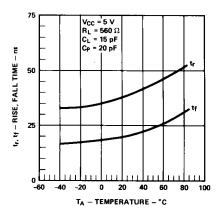
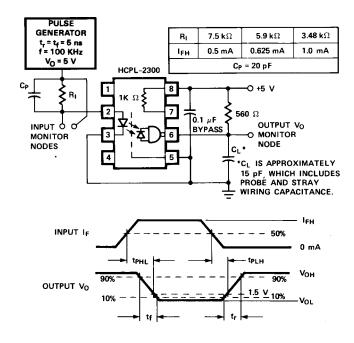
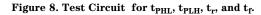


Figure 6. Typical Propagation Delay vs. Forward Current.

Figure 7. Typical Rise, Fall Time vs. Temperature.

Figure 5. Typical Propagation Delay vs. Temperature and Forward Current with and without Application of a Peaking Capacitor.





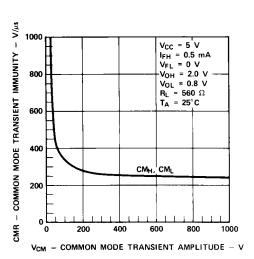


Figure 9. Typical Common Mode Transient Immunity vs. Common Mode Transient Amplitude.

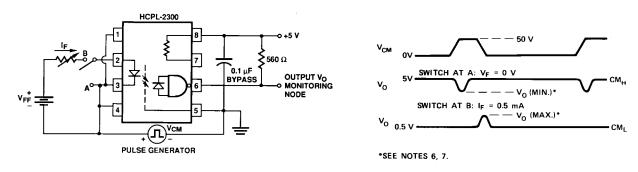


Figure 10. Test Circuit for Common Mode Transient Immunity and Typical Waveforms,

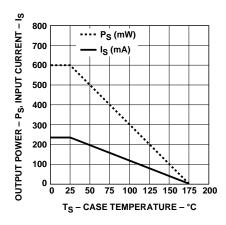


Figure 11. Thermal Derating Curve, Dependence of Safety Limiting Value with Case Temperature per VDE 0884.

#### **Applications**

The HCPL-2300 optocoupler has the unique combination of low 0.5 mA LED operating drive current at a 5 MBd speed performance. Low power supply current requirement of 10 mA maximum at 5.25 V and the ability to provide isolation between logic systems fulfills numerous applications ranging from logic level translations, line receiver and party line receiver applications, microprocessor I/O port isolation, etc. The open collector output allows for wired-OR arrangement. Specific interface

circuits are illustrated in Figures 12-16, and 18 with corresponding component values, performance data and recommended layout in Figures 17 and 19.

For -40°C to 85°C operating temperature range, a mid-range LED forward current (I<sub>F</sub>) of 0.625 mA is recommended in order to prevent overdriving the integrated circuit detector due to increased LED efficiency at temperatures between 0°C and -40°C. For narrower temperature range of 0°C to 85°C, a suggested operating LED current of 0.75 mA is recommended for the mid-range operating point and for minimal propagation delay skew. A peaking capacitance of 20 pF in parallel with the current limiting resistor for the LED shortens t<sub>PHL</sub> by approximately 33% and t<sub>PLH</sub> by 13%. Maintaining LED forward voltage (V<sub>F</sub>) below 0.8 V will guarantee that the HCPL-2300 output is off.

The recommended shunt drive technique for TTL/LSTTL/CMOS of Figure 12 provides for optimal speed performance, no leakage current path through the LED, and reduced common mode influences associated with series

switching of a "floating" LED. Alternate series drive techniques with either an active CMOS inverter or an open collector TTL/LSTTL inverter are illustrated in Figures 13 and 14 respectively. Open collector leakage current of 250  $\mu$ A has been compensated by the 3.16 K $\Omega$  resistor (Figure 14) at the expense of twice the operating forward current.

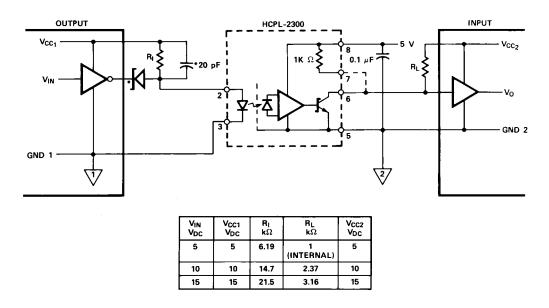
An application of the HCPL-2300 as an unbalanced line receiver for use in long line twisted wire pair communication links is shown in Figure 15. Low LED  $I_F$  and  $V_F$ allow longer line length, higher speed and multiple stations on the line in comparison to higher I<sub>F</sub>, V<sub>F</sub> optocouplers. Greater speed performance along with nearly infinite common mode immunity are achieved via the balanced split phase circuit of Figure 16. Basic balanced differential line receiver can be accomplished with one HCPL-2300 in Figure 16, but with a typical 400 V/µs common mode immunity. Data rate versus distance for both the above unbalanced and balanced line receiver applications are compared in Figure 17. The RS-232-C interface circuit of Figure 18

provides guaranteed minimum common mode immunity of  $100~V/\mu s$  while maintaining the 2:1 dynamic range of  $I_F$ .

A recommended layout for use with an internal 1000  $\Omega$  resistor

or an external pull-up resistor and required  $V_{\rm CC}$  bypass capacitor is given in Figure 19.  $V_{\rm CC1}$  is used with an external pull-up resistor for output voltage levels ( $V_{\rm O}$ ) greater than or equal to 5 V. As illustrated in Figure 19, an

optional  $V_{CC}$  and GND trace can be located between the input and the output leads of the HCPL-2300 to provide additional noise immunity at the compromise of insulation capability  $(V_{I-O})$ .



\*SCHOTTKY DIODE (HP 5082-2800, OR EQUIVALENT) AND 20 pF CAPACITOR ARE NOT REQUIRED FOR UNITS WITH OPEN COLLECTOR OUTPUT.

Figure 12. Recommended Shunt Drive Circuit for Interfacing between TTL/LSTTL/CMOS Logic Systems.

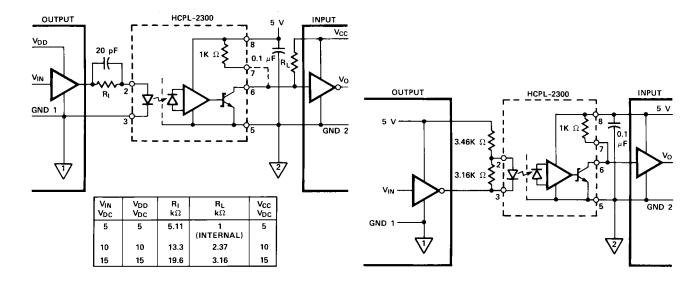


Figure 13. Active CMOS Series Drive Circuit.

Figure 14. Series Drive from Open Collector TTL/LSTTL Units.

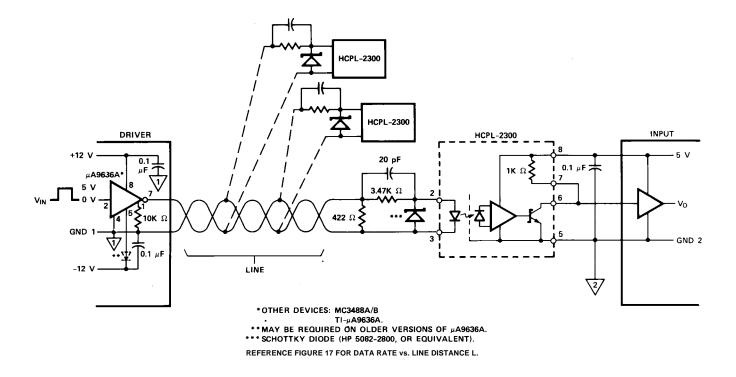


Figure 15. Application of HCPL-2300 as Isolated, Unbalanced Line Receiver(s).

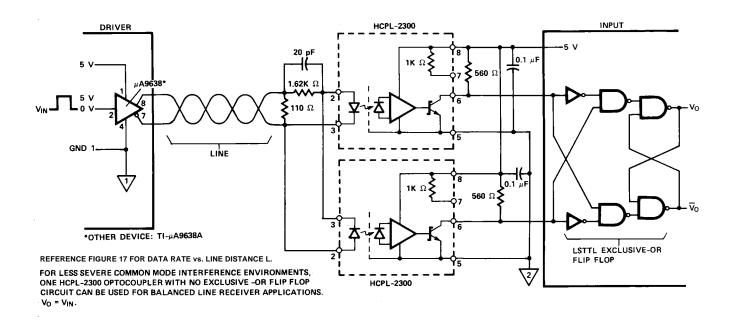


Figure 16. Application of Two HCPL-2300 Units Operating as an Isolated, High Speed, Balanced, Split Phase Line Receiver with Significantly Enhanced Common Mode Immunity.

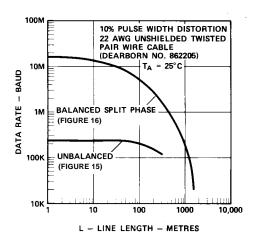


Figure 17. Typical Point to Point Data Rate vs. Length of Line for Unbalanced (Figure 15) and Balanced (Figure 16) Line Receivers Using HCPL-2300 Optocouplers.

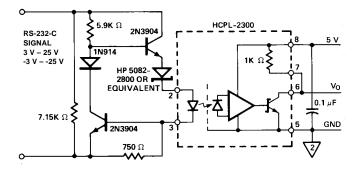


Figure 18. RS-232-C Interface Circuit with HCPL-2300.  $0^{\circ}\mathrm{C} < T_{A} < 85^{\circ}\mathrm{C}.$ 

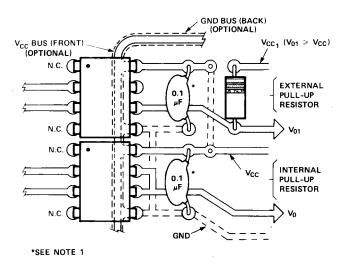


Figure 19. Recommended Printed Circuit Board Layout.

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